

View Online at <https://aerobasegroup.com/nsn/5961-01-047-9228>

Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open and 140.0 breakdown voltage, collector to emitter, with specified voltage between base and emitter

Current Rating Per Characteristic:

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

120.0 watts small-signal input power, common-collector preset

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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